

# PDTA143Z series

PNP resistor-equipped transistors;  
R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

Rev. 7 — 5 December 2011

Product data sheet

## 1. Product profile

### 1.1 General description

PNP Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

| Type number | Package |        |          | NPN complement | Package configuration |
|-------------|---------|--------|----------|----------------|-----------------------|
|             | NXP     | JEITA  | JEDEC    |                |                       |
| PDTA143ZE   | SOT416  | SC-75  | -        | PDTC143ZE      | ultra small           |
| PDTA143ZM   | SOT883  | SC-101 | -        | PDTC143ZM      | leadless ultra small  |
| PDTA143ZT   | SOT23   | -      | TO-236AB | PDTC143ZT      | small                 |
| PDTA143ZU   | SOT323  | SC-70  | -        | PDTC143ZU      | very small            |

### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

### 1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs
- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

### 1.4 Quick reference data

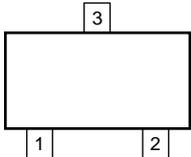
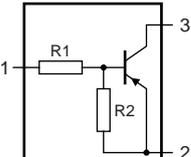
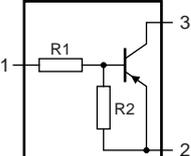
Table 2. Quick reference data

| Symbol           | Parameter                 | Conditions | Min | Typ | Max  | Unit       |
|------------------|---------------------------|------------|-----|-----|------|------------|
| V <sub>CEO</sub> | collector-emitter voltage | open base  | -   | -   | -50  | V          |
| I <sub>O</sub>   | output current            |            | -   | -   | -100 | mA         |
| R1               | bias resistor 1 (input)   |            | 3.3 | 4.7 | 6.1  | k $\Omega$ |
| R2/R1            | bias resistor ratio       |            | 8   | 10  | 12   |            |



## 2. Pinning information

**Table 3. Pinning**

| Pin                          | Description        | Simplified outline  | Graphic symbol  |
|------------------------------|--------------------|---|---|
| <b>SOT23; SOT323; SOT416</b> |                    |   |   |
| 1                            | input (base)       |  <p>006aaa144</p>            |  <p>sym003</p> |
| 2                            | GND (emitter)      |   |   |
| 3                            | output (collector) |   |   |
| <b>SOT883</b>                |                    |   |   |
| 1                            | input (base)       |  <p>Transparent top view</p> |  <p>sym003</p> |
| 2                            | GND (emitter)      |   |   |
| 3                            | output (collector) |   |   |

## 3. Ordering information

**Table 4. Ordering information**

| Type number | Package |   |         |
|-------------|---------|---|---------|
|             | Name    | Description   | Version |
| PDTA143ZE   | SC-75   | plastic surface-mounted package; 3 leads                                      | SOT416  |
| PDTA143ZM   | SC-101  | leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm | SOT883  |
| PDTA143ZT   | -       | plastic surface-mounted package; 3 leads                                      | SOT23   |
| PDTA143ZU   | SC-70   | plastic surface-mounted package; 3 leads                                      | SOT323  |

## 4. Marking

**Table 5. Marking codes**

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| PDTA143ZE   | 37                          |
| PDTA143ZM   | DP                          |
| PDTA143ZT   | *19                         |
| PDTA143ZU   | *47                         |

[1] \* = placeholder for manufacturing site code

## 5. Limiting values

**Table 6. Limiting values**

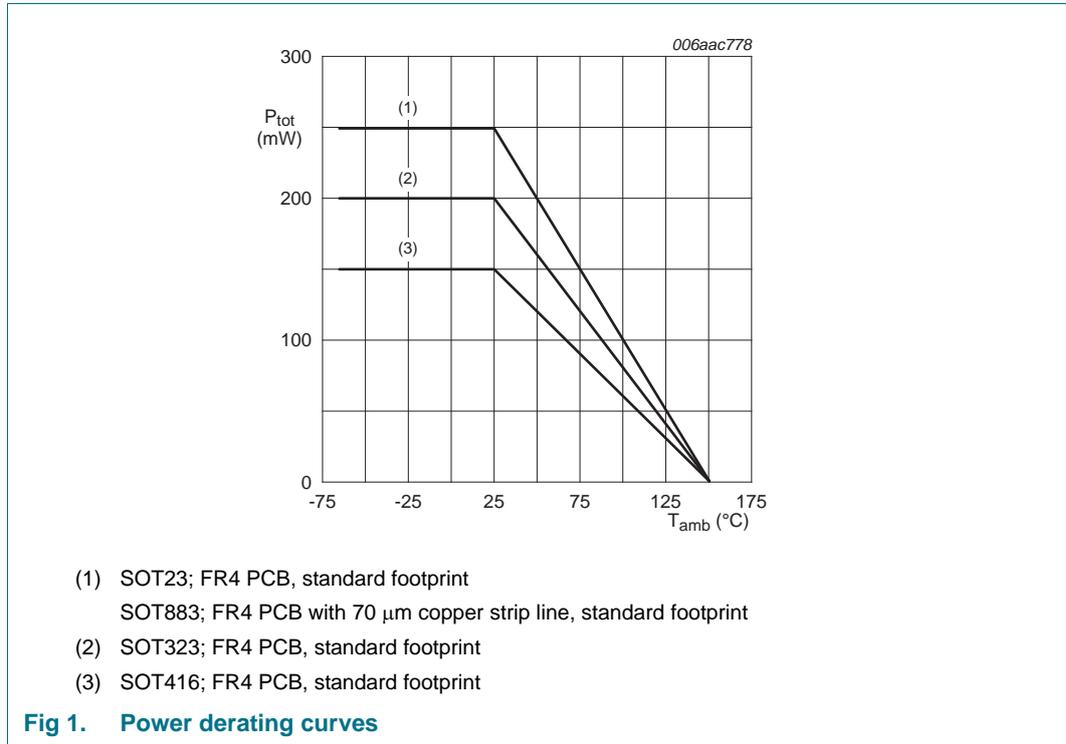
*In accordance with the Absolute Maximum Rating System (IEC 60134).*

| Symbol           | Parameter                 | Conditions                             | Min    | Max  | Unit |    |
|------------------|---------------------------|--|--------|------|------|----|
| V <sub>CBO</sub> | collector-base voltage    | open emitter                           | -      | -50  | V    |    |
| V <sub>CEO</sub> | collector-emitter voltage | open base                              | -      | -50  | V    |    |
| V <sub>EBO</sub> | emitter-base voltage      | open collector                         | -      | -5   | V    |    |
| V <sub>I</sub>   | input voltage             |  |        |      |      |    |
|                  | positive                  |  | -      | +5   | V    |    |
|                  | negative                  |  | -      | -30  | V    |    |
| I <sub>O</sub>   | output current            |  | -      | -100 | mA   |    |
| I <sub>CM</sub>  | peak collector current    | single pulse;<br>t <sub>p</sub> ≤ 1 ms | -      | -100 | mA   |    |
| P <sub>tot</sub> | total power dissipation   | T <sub>amb</sub> ≤ 25 °C               |        |      |      |    |
|                  | PDTA143ZE (SOT416)        |  | [1][2] | -    | 150  | mW |
|                  | PDTA143ZM (SOT883)        |  | [2][3] | -    | 250  | mW |
|                  | PDTA143ZT (SOT23)         |  | [1]    | -    | 250  | mW |
|                  | PDTA143ZU (SOT323)        |  | [1]    | -    | 200  | mW |
| T <sub>j</sub>   | junction temperature      |  | -      | 150  | °C   |    |
| T <sub>amb</sub> | ambient temperature       |  | -65    | +150 | °C   |    |
| T <sub>stg</sub> | storage temperature       |  | -65    | +150 | °C   |    |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70  $\mu$ m copper strip line, standard footprint.



## 6. Thermal characteristics

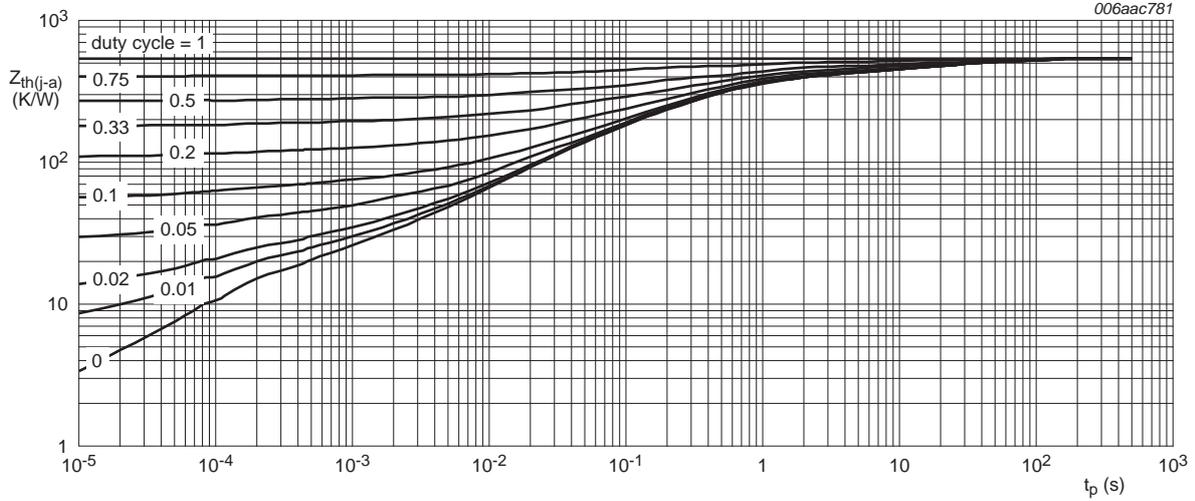
**Table 7. Thermal characteristics**

| Symbol               | Parameter                                   | Conditions  | Min | Typ | Max | Unit |
|----------------------|---|-------------|-----|-----|-----|------|
| R <sub>th(j-a)</sub> | thermal resistance from junction to ambient | in free air |     |     |     |      |
|                      | PDTA143ZE (SOT416)                          | [1][2]      | -   | -   | 830 | K/W  |
|                      | PDTA143ZM (SOT883)                          | [2][3]      | -   | -   | 500 | K/W  |
|                      | PDTA143ZT (SOT23)                           | [1]         | -   | -   | 500 | K/W  |
|                      | PDTA143ZU (SOT323)                          | [1]         | -   | -   | 625 | K/W  |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

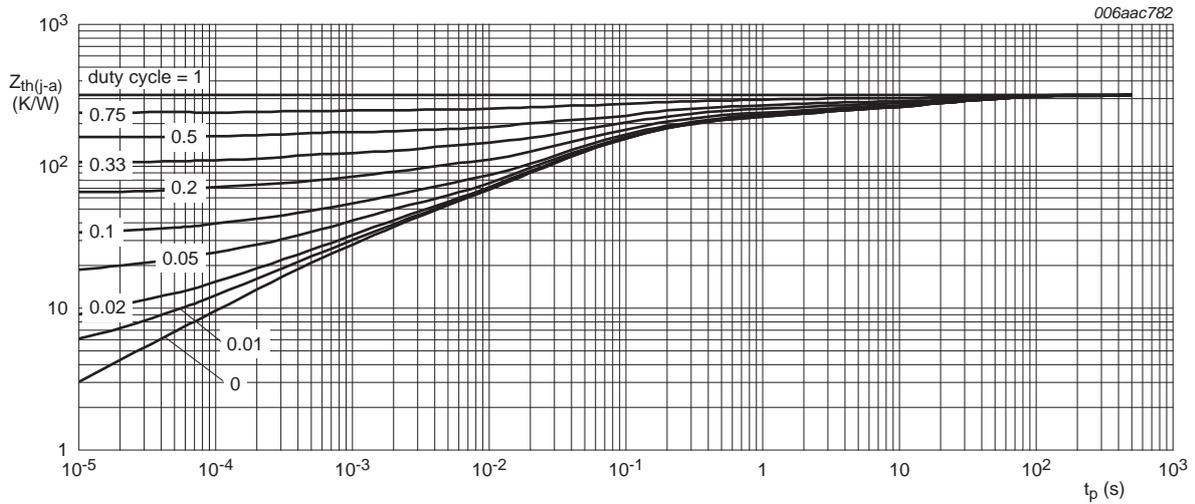
[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



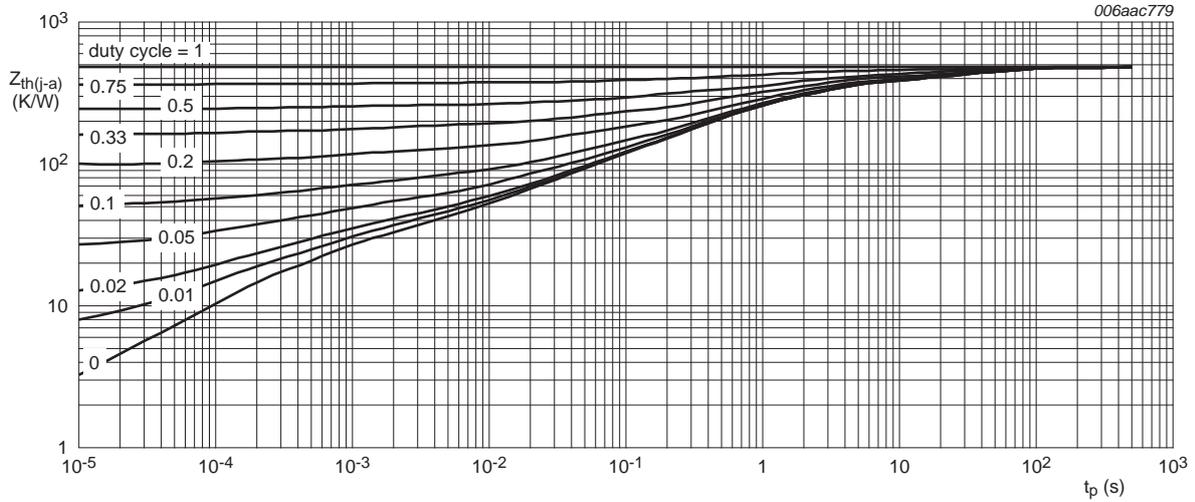
FR4 PCB, standard footprint

**Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143ZE (SOT416); typical values**



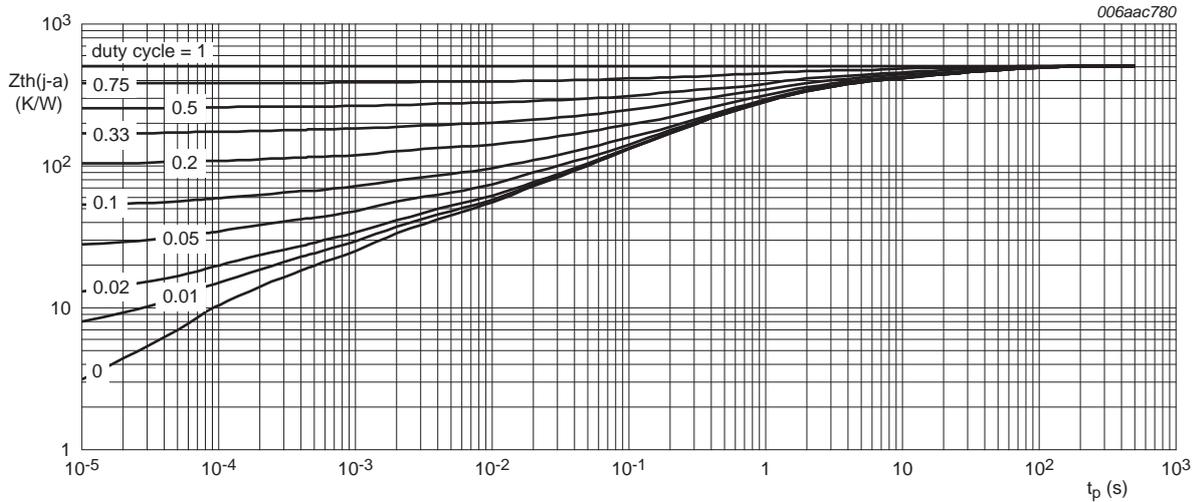
FR4 PCB, 70 μm copper strip line

**Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143ZM (SOT883); typical values**



FR4 PCB, standard footprint

**Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143ZT (SOT23); typical values**



FR4 PCB, standard footprint

**Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143ZU (SOT323); typical values**

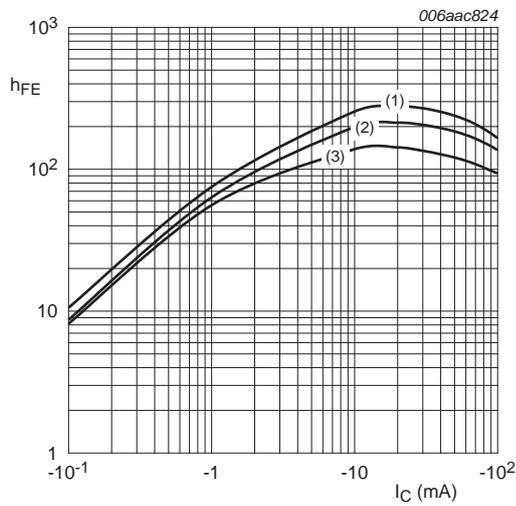
## 7. Characteristics

**Table 8. Characteristics**

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

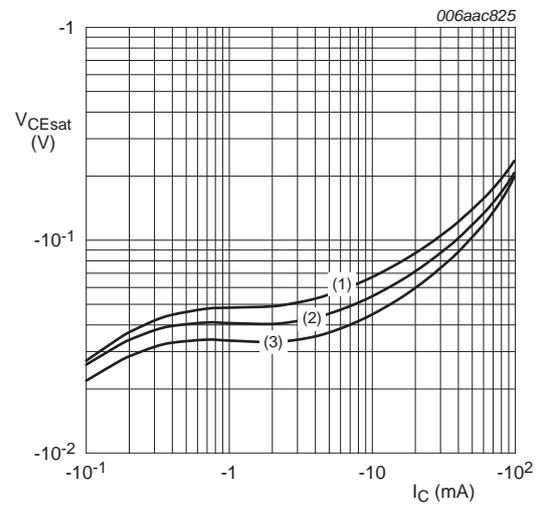
| Symbol       | Parameter                            | Conditions   | Min  | Typ  | Max  | Unit          |
|--------------|--------------------------------------|--|------|------|------|---------------|
| $I_{CBO}$    | collector-base cut-off current       | $V_{CB} = -50\text{ V}$ ; $I_E = 0\text{ A}$   | -    | -    | -100 | nA            |
| $I_{CEO}$    | collector-emitter cut-off current    | $V_{CE} = -30\text{ V}$ ; $I_B = 0\text{ A}$   | -    | -    | -1   | $\mu\text{A}$ |
|              |                                      | $V_{CE} = -30\text{ V}$ ; $I_B = 0\text{ A}$ ;<br>$T_j = 150\text{ }^{\circ}\text{C}$        | -    | -    | -5   | $\mu\text{A}$ |
| $I_{EBO}$    | emitter-base cut-off current         | $V_{EB} = -5\text{ V}$ ; $I_C = 0\text{ A}$  | -    | -    | -170 | $\mu\text{A}$ |
| $h_{FE}$     | DC current gain                      | $V_{CE} = -5\text{ V}$ ; $I_C = -10\text{ mA}$   | 100  | -    | -    |               |
| $V_{CEsat}$  | collector-emitter saturation voltage | $I_C = -5\text{ mA}$ ; $I_B = -0.25\text{ mA}$   | -    | -    | -100 | mV            |
| $V_{I(off)}$ | off-state input voltage              | $V_{CE} = -5\text{ V}$ ; $I_C = -100\text{ }\mu\text{A}$                                     | -    | -0.6 | -0.5 | V             |
| $V_{I(on)}$  | on-state input voltage               | $V_{CE} = -0.3\text{ V}$ ; $I_C = -5\text{ mA}$  | -1.3 | -0.9 | -    | V             |
| R1           | bias resistor 1 (input)              |  | 3.3  | 4.7  | 6.1  | k $\Omega$    |
| R2/R1        | bias resistor ratio                  |  | 8    | 10   | 12   |               |
| $C_c$        | collector capacitance                | $V_{CB} = -10\text{ V}$ ; $I_E = i_e = 0\text{ A}$ ;<br>$f = 1\text{ MHz}$                   | -    | -    | 3    | pF            |
| $f_T$        | transition frequency                 | $V_{CE} = -5\text{ V}$ ; $I_C = -10\text{ mA}$ ; <a href="#">[1]</a><br>$f = 100\text{ MHz}$ | -    | 180  | -    | MHz           |

[1] Characteristics of built-in transistor



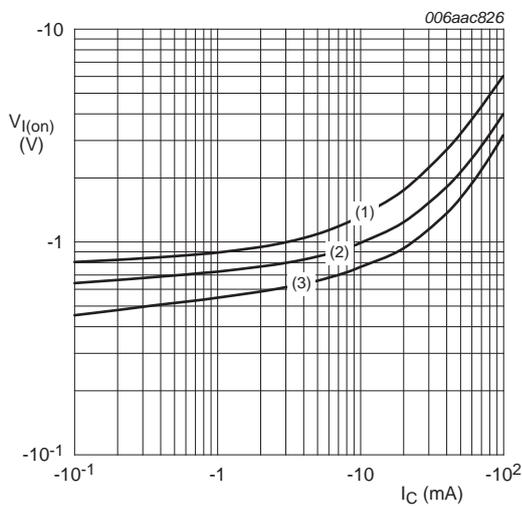
$V_{CE} = -5 \text{ V}$   
 (1)  $T_{amb} = 100 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -40 \text{ }^\circ\text{C}$

**Fig 6. DC current gain as a function of collector current; typical values**



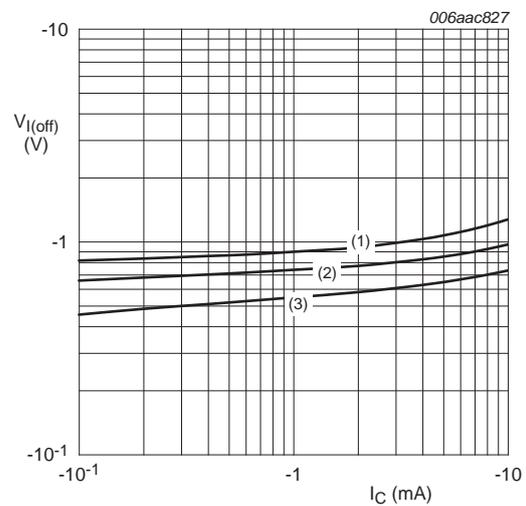
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -40 \text{ }^\circ\text{C}$

**Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values**



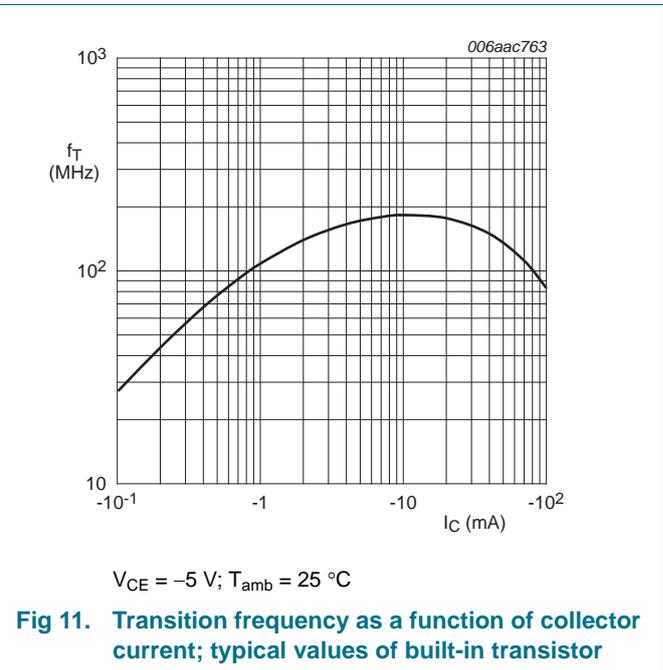
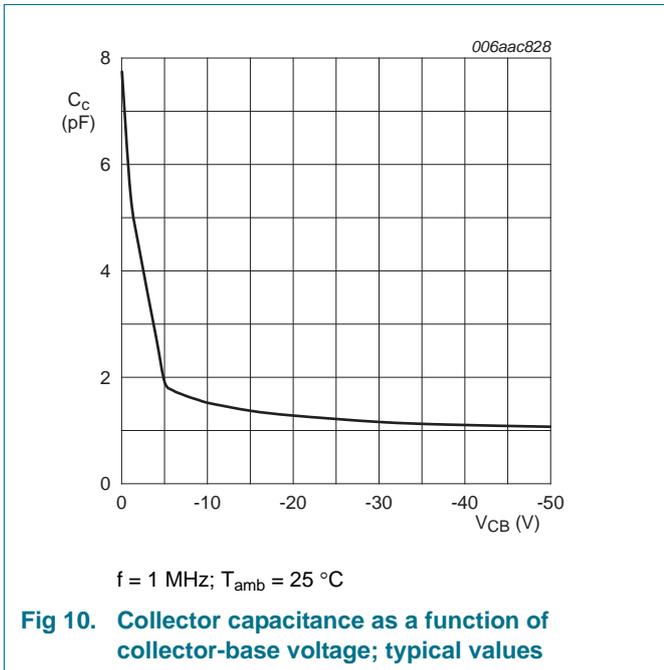
$V_{CE} = -0.3 \text{ V}$   
 (1)  $T_{amb} = -40 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100 \text{ }^\circ\text{C}$

**Fig 8. On-state input voltage as a function of collector current; typical values**



$V_{CE} = -5 \text{ V}$   
 (1)  $T_{amb} = -40 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100 \text{ }^\circ\text{C}$

**Fig 9. Off-state input voltage as a function of collector current; typical values**

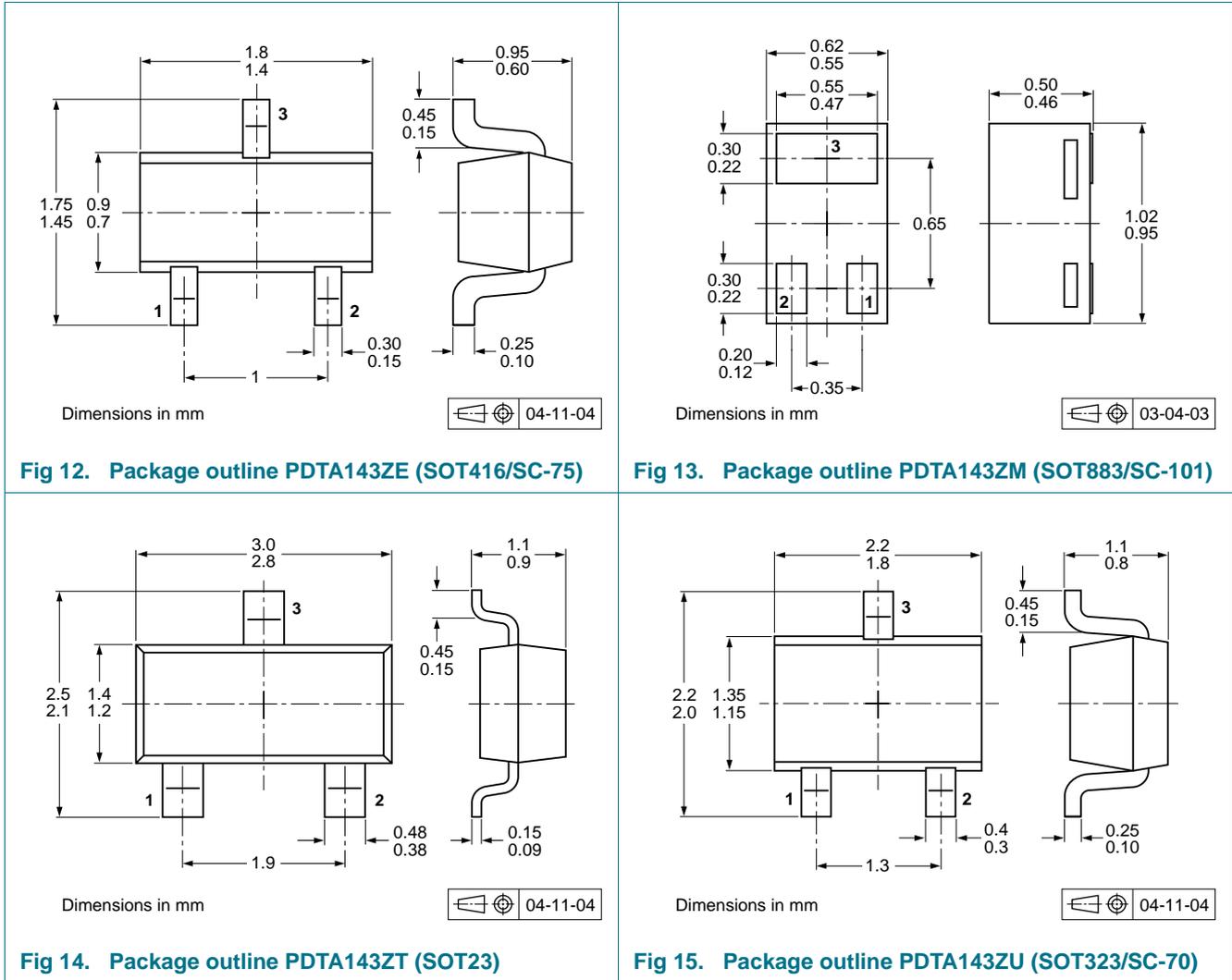


## 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

**9. Package outline**



**10. Packing information**

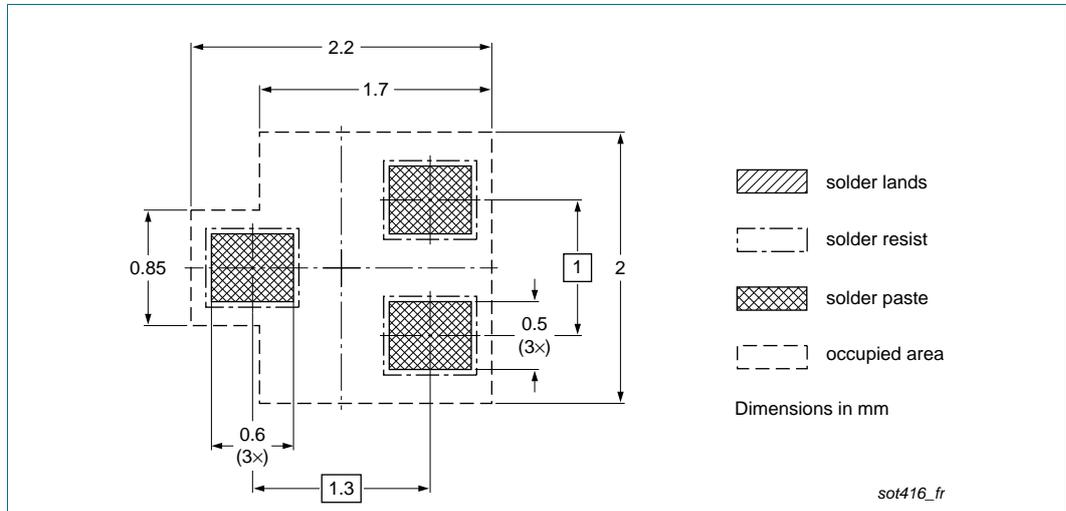
**Table 9. Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

| Type number | Package | Description                    | Packing quantity |      |       |
|-------------|---------|--------------------------------|------------------|------|-------|
|             |         |                                | 3000             | 5000 | 10000 |
| PDTA143ZE   | SOT416  | 4 mm pitch, 8 mm tape and reel | -115             | -    | -135  |
| PDTA143ZM   | SOT883  | 2 mm pitch, 8 mm tape and reel | -                | -    | -315  |
| PDTA143ZT   | SOT23   | 4 mm pitch, 8 mm tape and reel | -215             | -    | -235  |
| PDTA143ZU   | SOT323  | 4 mm pitch, 8 mm tape and reel | -115             | -    | -135  |

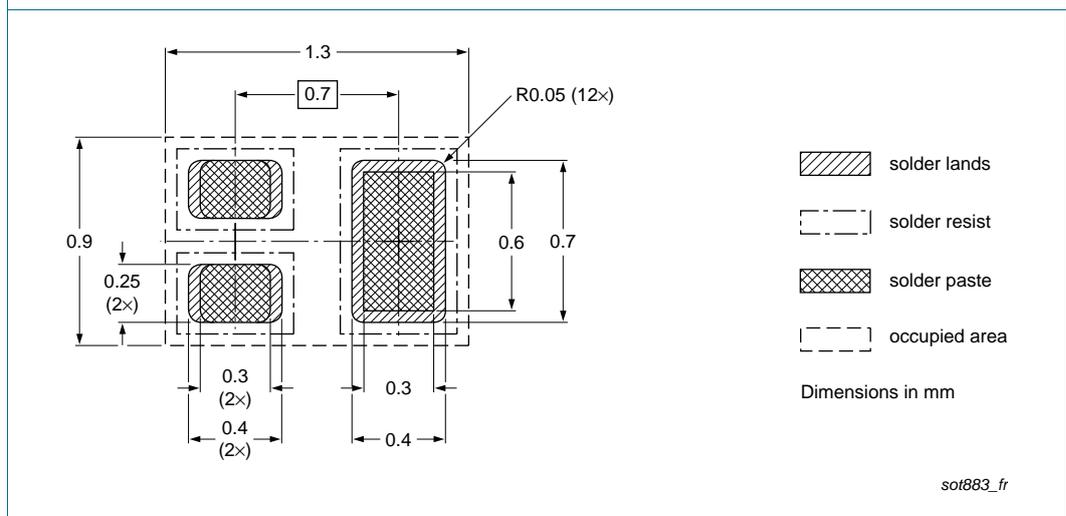
[1] For further information and the availability of packing methods, see [Section 14](#).

**11. Soldering**



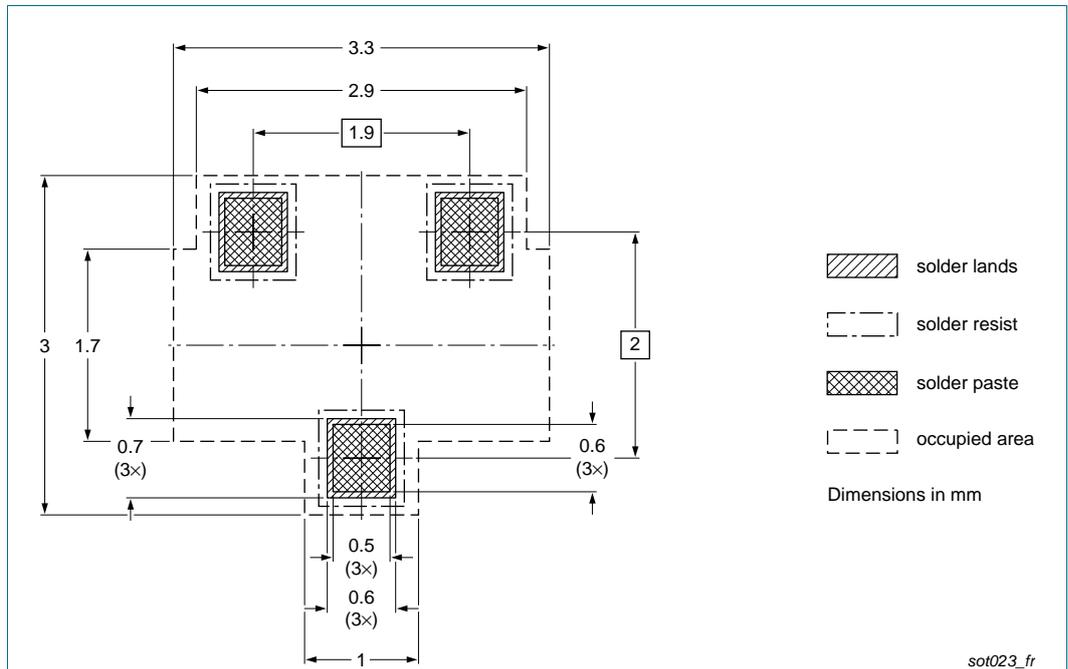
Reflow soldering is the only recommended soldering method.

**Fig 16. Reflow soldering footprint PDTA143ZE (SOT416/SC-75)**

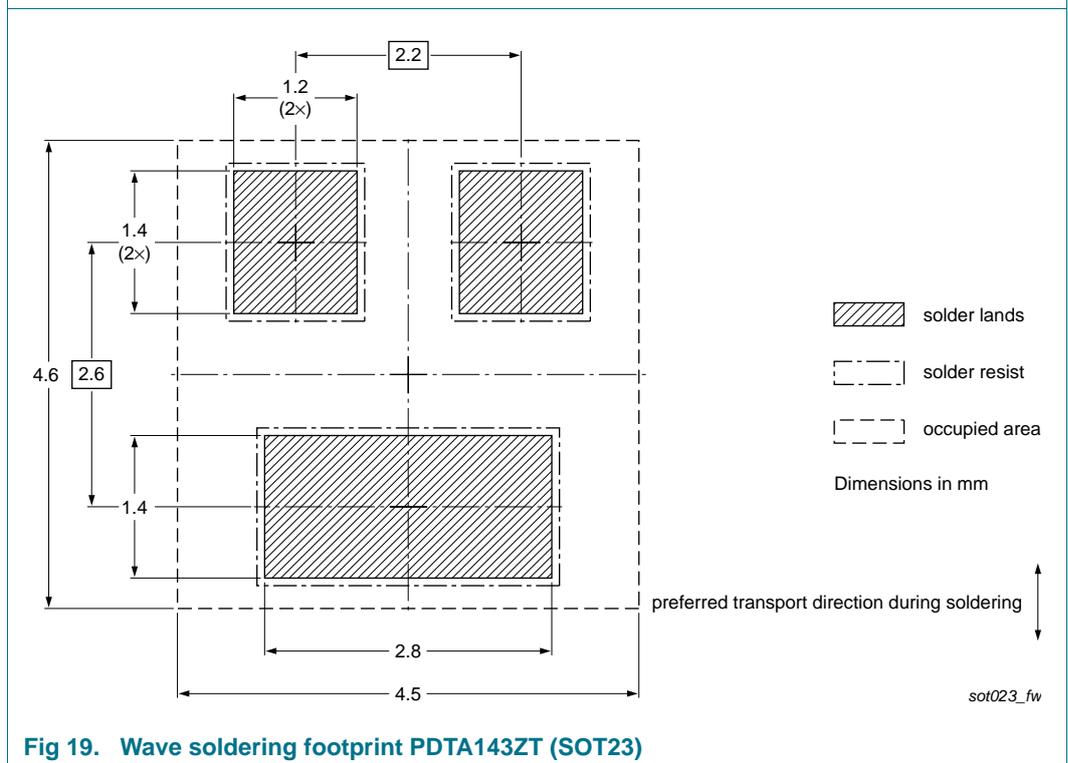


Reflow soldering is the only recommended soldering method.

**Fig 17. Reflow soldering footprint PDTA143ZM (SOT883/SC-101)**



**Fig 18. Reflow soldering footprint PDTA143ZT (SOT23)**



**Fig 19. Wave soldering footprint PDTA143ZT (SOT23)**

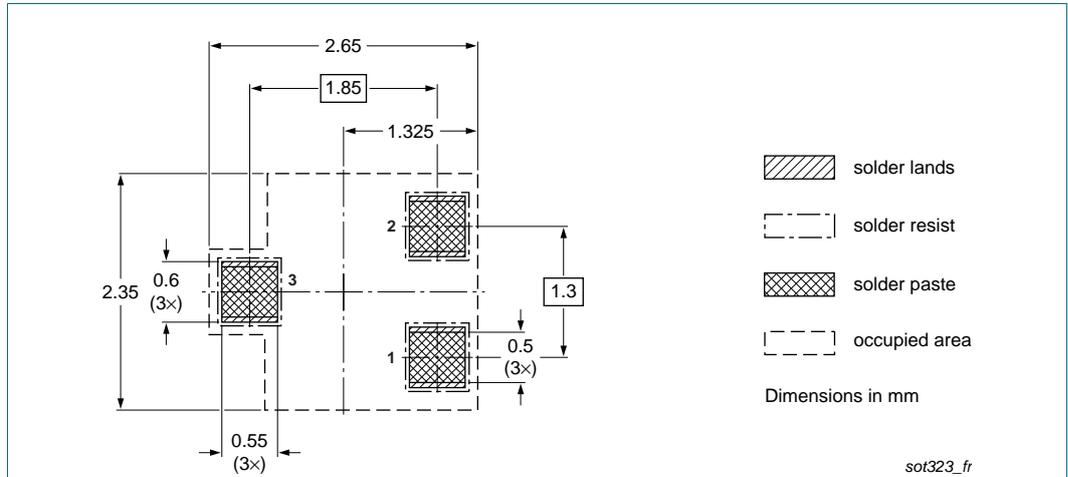


Fig 20. Reflow soldering footprint PDTA143ZU (SOT323/SC-70)

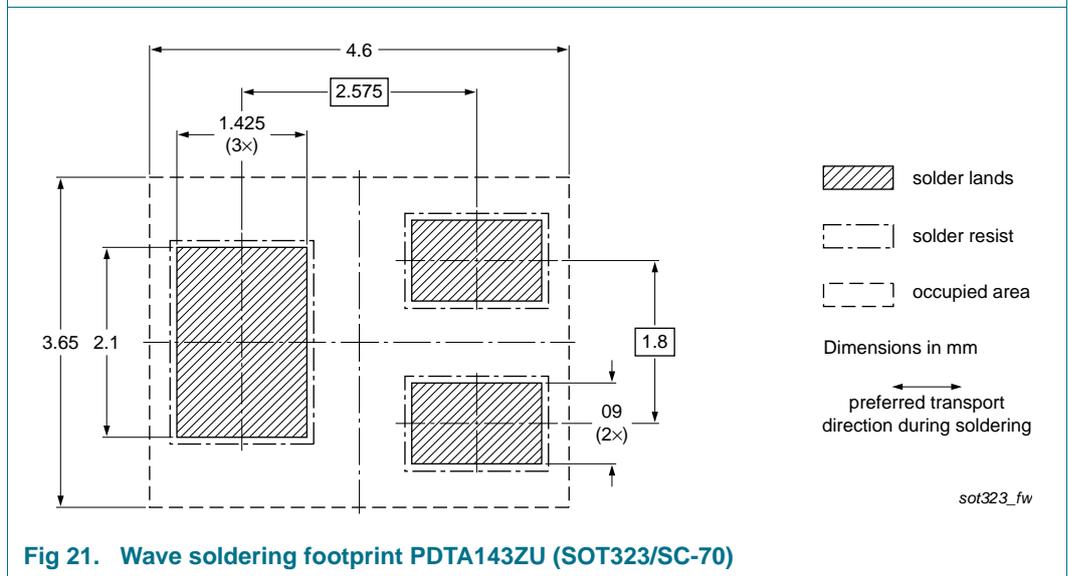


Fig 21. Wave soldering footprint PDTA143ZU (SOT323/SC-70)